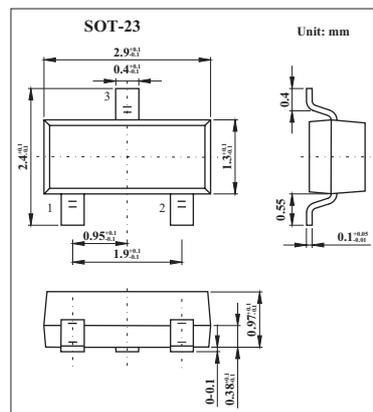


# BAT720

## ■ Features

- Ultra high switching speed
- Low forward current
- Guard ring protected
- Small plastic SMD package



## ■ Absolute Maximum Ratings Ta = 25°C

| Parameter                                   | Symbol              | Conditions             | Min | Max  | Unit |
|---|---------------------|------------------------|-----|------|------|
| Continuous reverse voltage                  | V <sub>R</sub>      |                        |     | 40   | V    |
| Continuous forward current                  | I <sub>F</sub>      |                        |     | 500  | mA   |
| Non-repetitive peak forward current         | I <sub>FSM</sub>    | t <sub>p</sub> < 10 ms |     | 2    | A    |
| Storage temperature                         | T <sub>stg</sub>    |                        | -65 | +150 | °C   |
| Junction temperature                        | T <sub>j</sub>      |                        |     | 125  | °C   |
| thermal resistance from junction to ambient | R <sub>th j-a</sub> |                        |     | 500  | K/W  |

Note

1. Pulse test: t<sub>p</sub> < 300 μs; δ ≤ 0.02.

## ■ Electrical Characteristics Ta = 25°C

| Parameter         | Symbol         | Conditions                                     | Min | Max | Unit |
|-------------------|----------------|--|-----|-----|------|
| Forward voltage   | V <sub>F</sub> | I <sub>F</sub> = 500 mA                        |     | 550 | mV   |
| Reverse current   | I <sub>R</sub> | V <sub>R</sub> = 35 V                          |     | 100 | μA   |
|                   |                | V <sub>R</sub> = 35 V; T <sub>j</sub> = 100 °C |     | 10  | mA   |
| Diode capacitance | C <sub>d</sub> | f = 1 MHz; V <sub>R</sub> = 0 V;               | 60  | 90  | pF   |

## ■ Marking

|         |     |
|---------|-----|
| Marking | L6p |
|---------|-----|